

N-channel 40 V, 0.97 mOhm, Standard level MOSFET in LFPAK56

4 January 2024

Product data sheet

1. General description

Automotive qualified N-channel MOSFET using the latest Trench 15 low ohmic enhanced-Trench Bottom Oxide (e-TBO) technology, providing high ruggedness at low R_{DSon}, housed in an LFPAK56 package. This product has been fully designed and qualified to meet AEC-Q101 requirements delivering high performance and endurance.

2. Features and benefits

- Fully automotive qualified to AEC-Q101:
 - 175 °C rating suitable for thermally demanding environments
- Trench 15 e-TBO technology:
 - Merging benefits of Superjunction technology (high ruggedness) and Split-Gate technology (low R_{DSon})
- · Fast and efficient switching with high damping and low spiking
- Tight $V_{GS(th)}$ limits enable easy paralleling of MOSFETs
- LFPAK Gull Wing leads:
 - High Board Level Reliability absorbing mechanical stress during thermal cycling, unlike traditional QFN packages
 - · Visual (AOI) soldering inspection, no need for expensive x-ray equipment
 - · Easy solder wetting for good mechanical solder joints
- LFPAK copper clip technology:
 - Improved reliability, with reduced Rth, RDSon and package inductance
 - Increases maximum current capability and improved current spreading

3. Applications

- 12 V automotive systems
- Motor, lighting and solenoid control
- Reverse battery protection
- Ultra high-performance power switching

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	320	A
Static charact	eristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12		0.57	0.81	0.97	mΩ

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Dynamic chara	cteristics					
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 32 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 14; Fig. 15</u>	81	135	189	nC

[1] This current had been successfully demonstrated during product characterisation. In practical applications the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	S	source	mb					
2	S	source		D				
3	S	source	a					
4	G	gate		G_(₽, ₽)				
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	mbb076 S				

6. Ordering information

Table 3. Ordering information			
	Name	Description	Version
BUK7Y1R0-40N	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK7Y1R0-40N	71N040Y

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). T_i = 25 °C unless otherwise stated.

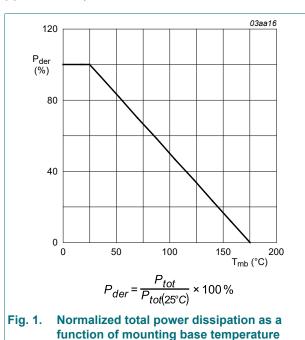
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	40	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	268	W
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	320	А
				-	262	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu$ s; $T_{mb} = 25 \ ^{\circ}C$; <u>Fig. 3</u> ; Fig. 4	[1]	-	1465	A
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Source-drain	n diode					_
I _S	source current	T _{mb} = 25 °C	[1]	-	268	А
I _{SM}	peak source current	pulsed; t _p ≤ 10 µs; T _{mb} = 25 °C		-	1465	А
Avalanche r	uggedness	1				
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$\begin{array}{l} I_{D} = 190 \; \text{A}; \; V_{sup} \leq \; 40 \; \text{V}; \; R_{GS} = 50 \; \Omega; \\ V_{GS} = 10 \; \text{V}; \; T_{j(init)} = 25 \; ^{\circ}\text{C}; \; unclamped; \\ \hline Fig. \; 5 \end{array}$	[2] [3]	-	145	mJ
I _{AS}	non-repetitive avalanche current		[4]	-	190	A

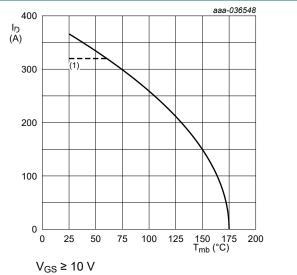
[1] This current had been successfully demonstrated during product characterisation. In practical applications the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

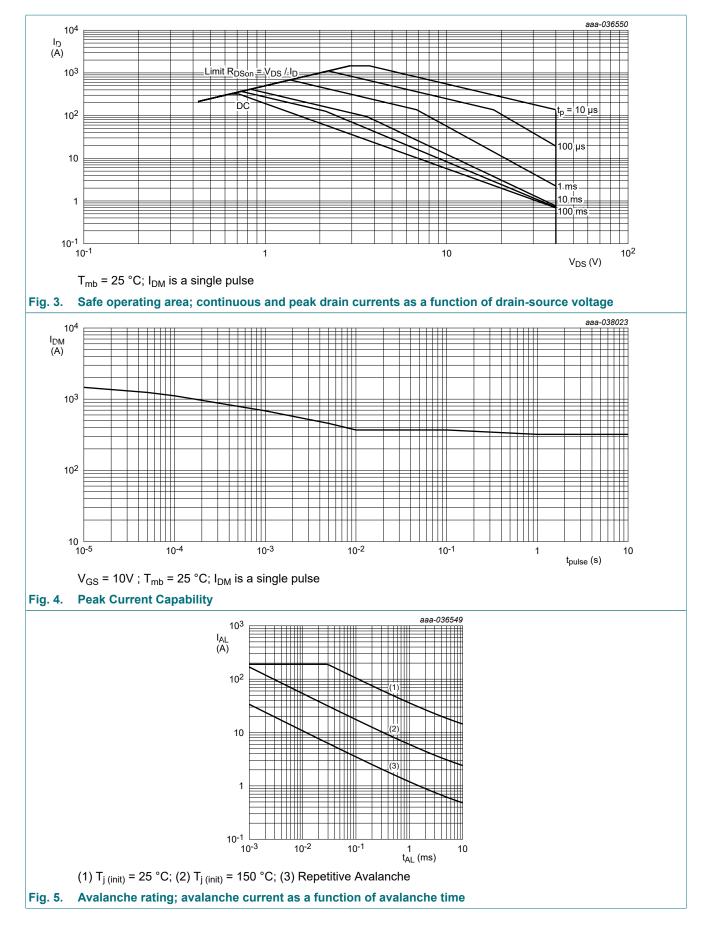
[4] Protected by 100% test.





(1) 320 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

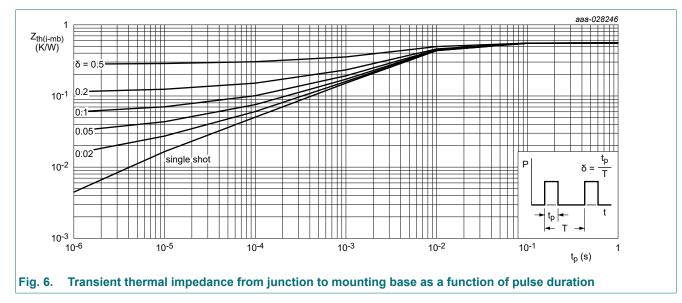
Fig. 2. Continuous drain current as a function of mounting base temperature



9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. <u>6</u>		-	0.48	0.56	K/W
R _{th(j-a)}	thermal resistance from junction to ambient		[1]	-	24	-	K/W

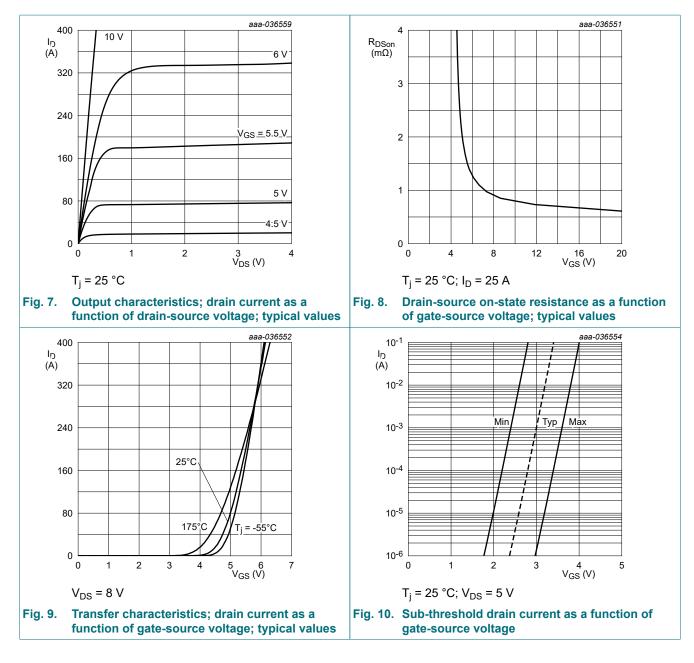
[1] Device on 4 layer PCB. Refer to TN00008 for further information.



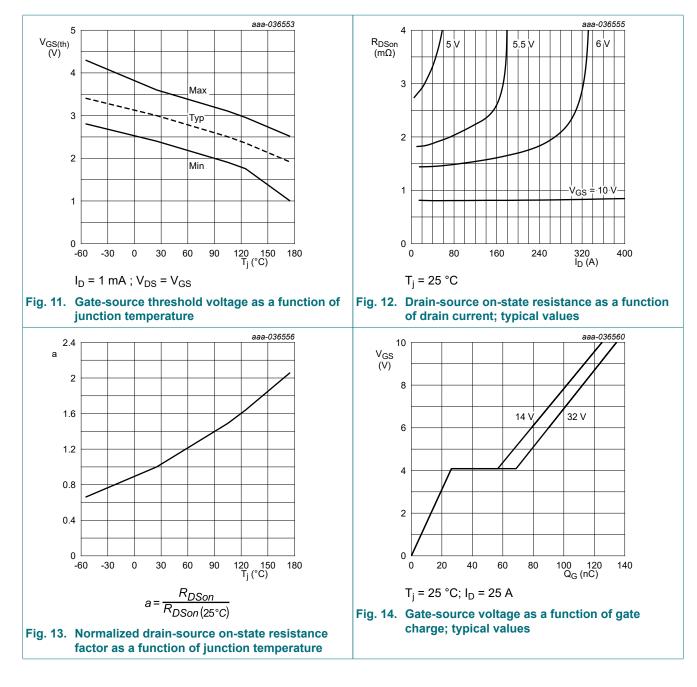
10. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Static chara	acteristics						
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C		40	43	-	V
. ,	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -40 °C		-	40.5	-	V
		I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C		36	40	-	V
V _{GS(th)}	gate-source threshold	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C; <u>Fig. 10</u>		2.4	3	3.6	V
()	voltage	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 11</u>		-	-	4.3	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C; Fig. 11		1	-	-	V
I _{DSS}	drain leakage current	V _{DS} = 40 V; V _{GS} = 0 V; T _i = 25 °C		-	0.1	1	μA
		V _{DS} = 16 V; V _{GS} = 0 V; T _i = 125 °C		-	1.1	10	μA
		V _{DS} = 40 V; V _{GS} = 0 V; T _j = 175 °C		-	80	500	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C		-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C		-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12		0.57	0.81	0.97	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 105 °C; Fig. 13		0.77	1.15	1.46	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 125 °C; Fig. 13		0.84	1.25	1.6	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 13		1	1.52	2	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C		0.2	0.63	1.6	Ω
Dynamic cł	naracteristics	· · ·				-	
Q _{G(tot)}	total gate charge $I_D = 25 \text{ A}; V_{DS} = 32 \text{ V}; V_{GS} = 10 \text{ V};$			81	135	189	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 14;</u> <u>Fig. 15</u>		14	26	38	nC
Q _{GD}	gate-drain charge	-		12	42	72	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz;		4552	7587	10622	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 16</u>		1166	1666	2166	pF
C _{rss}	reverse transfer capacitance			252	631	1010	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; R _L = 1.2 Ω; V _{GS} = 10 V;		-	25	-	ns
t _r	rise time	R _{G(ext)} = 5 Ω; T _j = 25 °C		-	49	-	ns
t _{d(off)}	turn-off delay time			-	79	-	ns
t _f	fall time	1		-	58	-	ns
Source-dra	in diode					-	
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 17</u>		-	0.79	1	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	34	-	ns
Q _r	recovered charge	V _{DS} = 20 V; T _j = 25 °C; <u>Fig. 18</u>	[1]	-	24	-	nC

[1] includes capacitive recovery

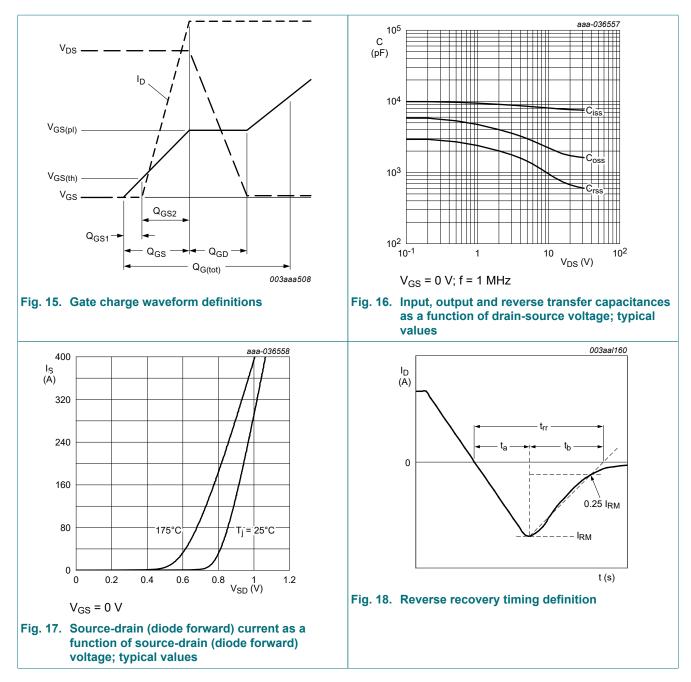


Product data sheet



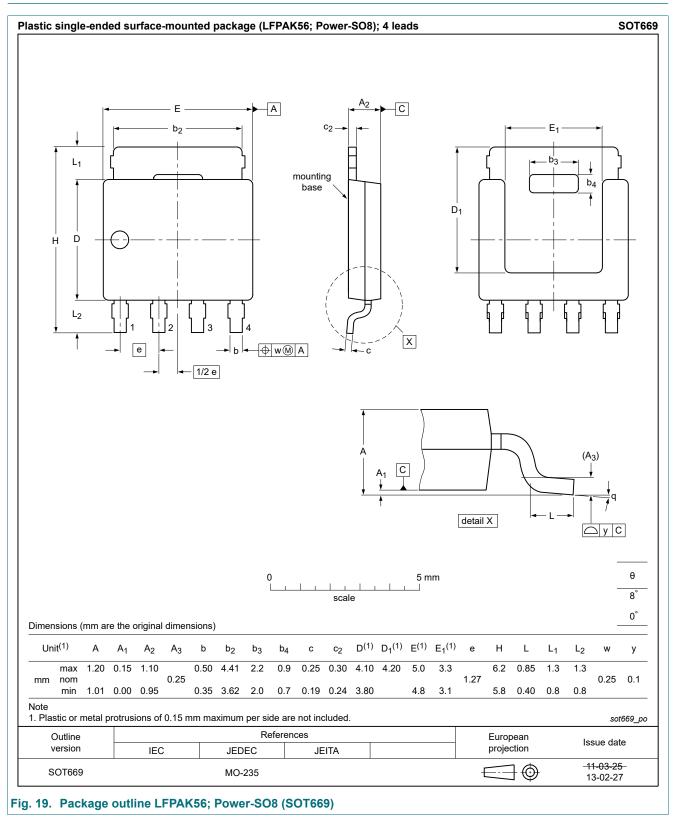
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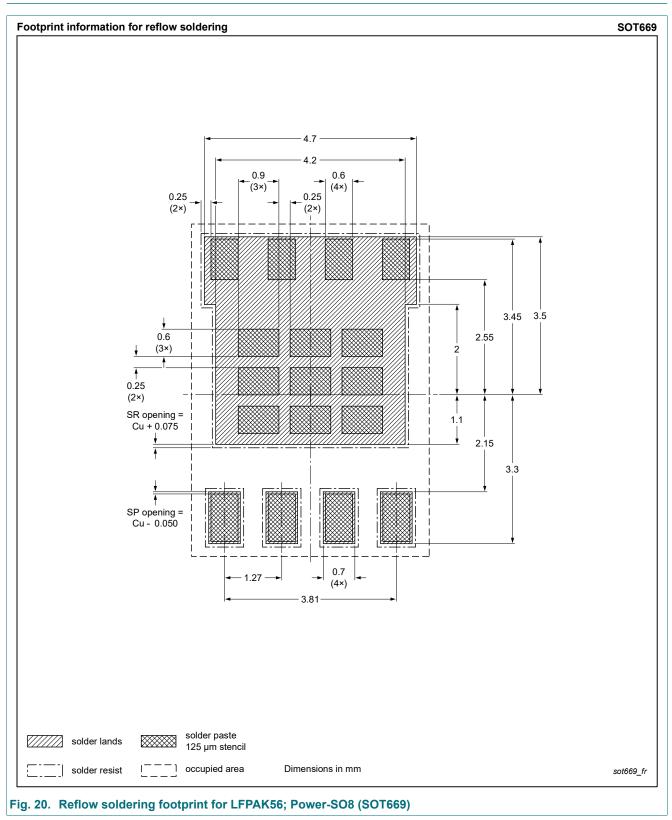


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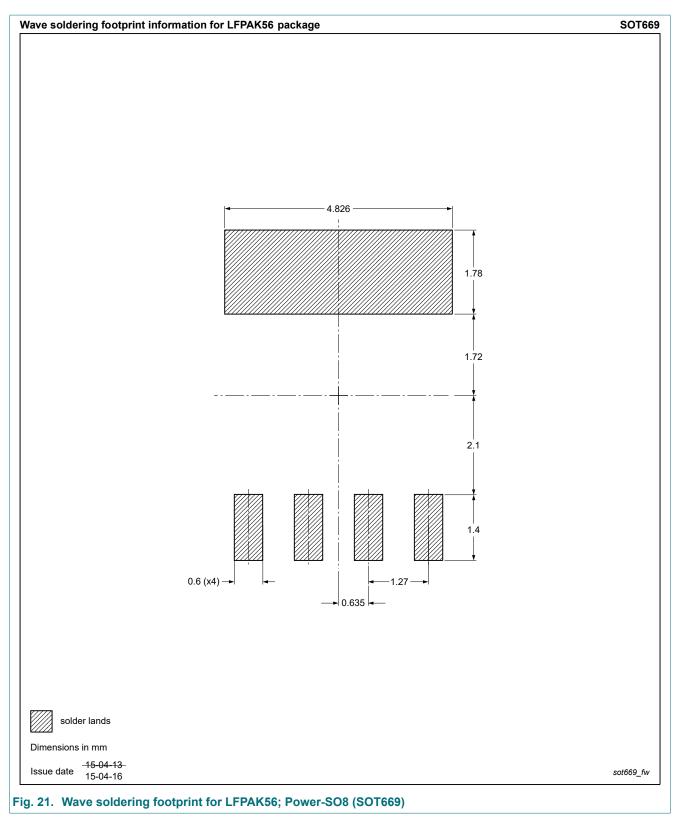
11. Package outline



12. Soldering



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13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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